

Features

- Voltages from 6.3VDC to 500VDC+
- Available in EIA sizes from 0402 to 1812 depending on voltage rating.
- Effective attenuation from 100KHz to 17GHz with various bandwidths.
- · Designed to attenuate unwanted electromagnetic interference such as noise or spurious emissions at specific frequencies.
- · Can be used in both single ended (one source signal) and differential (+/- signal) applications.
- AEC-Q200 automotive qualification (as required)

Common Applications:

- · Power Bypass
- FPGA / ASIC / μ-P Decoupling
- · Amplifier Filter & Decoupling
- DC-DC Converter Designs
- · High Speed Data Filtering
- DC Drives & Motors
- Mil/Aero Electronics
- Medical Electronics
- Wireless Charging
- GSM/Antennas
- EMC I/O Filtering
- Electric Vehicles
- IT & Networking
- Industrial

Expert Design Support:

At Johanson, we understand the complexity and difficulty associated in dealing with unwanted X2Y EMI issues in your circuit

With this in mind, we have a dedicated team of X2Y EMC experts in-house who are ready to support you. Our experienced engineers are here to help solve X2Y EMI issues and can support you with:

- Identifying the right component(s) to solve your unwanted X2Y EMI spikes.
- · How to design-in and connect Johanson EMI Filters to your product's schematic to achieve the most effective results.
- Reviewing and optimize your PCB layout, and where required, advise on any necessary changes that can be made to improve EM compliance.

S21 Plottter Tool:

Try out Johanson's S21 Plotter, an on-line tool for designers to quickly select different values or sizes and see the responses of each configuration: Visit JOHANSON Dielectrics website at: https://s21plotter.johansondielectrics.com/





X2Y EMI Filters Capacitance Values & How to Order

Capacitance Values

EMI Filte (1 Y-Ca		<10pF	10pF	22pF	27pF	33pF	47pF	100pF	220pF	470pF	1000pF	1500pF	2200pF	4700pF	.010µF	.015µF	.022µF	.039µF	.047µF	0.10µF	0.18µF	0.22µF	0.33µF	0.40µF	0.47µF	1.0µF
Power By (2 Y-Cap		<20pF	20pF	44pF	54pF	66pF	94pF	200pF	440pF	940pF	2000pF	3000pF	4400pF	9400pF	.020µF	.030µF	.044µF	.078µF	.094µF	0.20µF	0.36µF	0.44µF	0.66µF	0.80µF	0.94µF	2.0µF
Power Bypass	CAP.	XRX	100	220	270	330	470	101	221	471	102	152	222	472	103	153	223	393	473	104	184	224	334	404	474	105
0402	NP0	50	50	50	50	50	50	50																		
0402	X7R								50	50	50	50	50	50	16											
0603	NP0	100	100	100	100	100	100	50	50																	
0603	X7R						100	100	100	100	100	100	100	100	50	25	25		16	10		10				
0005	NP0		100	100	100	100	100	100	100	50																
0805	X7R							100	100	100	100	100	100	100	100	50	50		50	25						
1000	NP0										100															
1206	X7R			V	OLTAG	3F									100	100	100		100	100*		16	16		10	
1210	X7R			6.3 10	ATING = 6.3 \ = 10 \ = 16 \	SS VDC /DC									500					100		100	100		25	16
1410	X7R			25 : 50 : 100 :	= 25 V = 50 V = 100	/DC /DC VDC										500								100		
1812	X7R			500	= 500	VDC												500							100	

Automotive version currently available for those values only

HOW TO ORDER

EM	CF	500	G	100	M	1	GF	001	В
Subfamily	Size	Voltage	DTC	Capacitance	Tol	Mark	Termination	Special Code	Pack
EM = EMI Filters	CF = 0402 CP = 0603 CT = 0805 DD = 1206 DF = 1210 DK = 1410 DR = 1812	6R3 = 6.3 V 100 = 10 V 160 = 16 V 250 = 25 V 500 = 50 V 101 = 100 V 501 = 500 V	G = NP0/C0G W = X7R	1st two digits are significant; third digit denotes number of zeros. 101 = 100 pF 102 = 1000 pF	A = ±0.05pF M = ±20%	1 = No Mark	GV = Ni/Sn (RoHs) GF = Polyterm Sn (RoHs) NW = Polyterm Sn/Pb	001 = Default catalog item	B = Bulk E = 7" Reel Emb Tape

Example: EMCF500G100M1GF001B EMI Filters, PME, 0402, NP0/C0G, 50.0V, 10.000pF±20%, Polyterm Sn (RoHS), Bulk

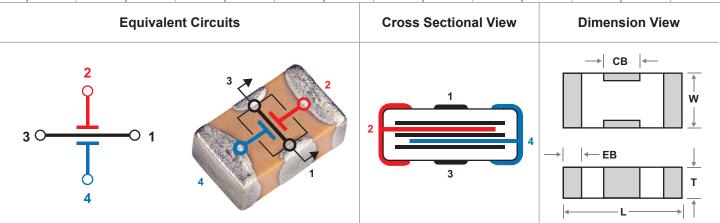




Mechanical & Electrical Characteristics

Mechanical Characteristics

	EIA 0402 EMCF Series		EIA 0603 EMCP Series		EIA 0805 EMCT Series		EIA 1206 EMDD Series			1210 Series		1410 Series	EIA 1812 EMDR Series		
	In	mm	In	mm	In	mm	In	mm	In	mm	In	mm	In	mm	
L	0.045	1.143	0.064	1.626	0.080	2.032	0.124	3.150	0.125	3.175	0.140	0.140	0.174	4.420	
	± 0.003	± 0.076	± 0.005	± 0.127	± 0.008	± 0.203	± 0.010	± 0.254	± 0.010	± 0.254	± 0.010	± 0.010	± 0.010	± 0.254	
w	0.025	0.635	0.064	0.889	0.050	1.270	0.063	1.600	0.098	2.489	0.098	2.490	0.125	3.175	
	± 0.003	± 0.076	± 0.005	± 0.127	± 0.008	± 0.203	± 0.010	± 0.254	± 0.010	± 0.254	± 0.010	± 0.254	± 0.010	± 0.254	
т	0.02	0.508	0.26	0.660	0.040	1.016	0.050	1.270	0.070	1.778	0.070	1.778	0.090	2.286	
	max.	max.	max	max.	max	max.	max.	max.	max	max	max.	max.	max	max.	
ЕВ	0.008	0.203	0.010	0.254	0.012	0.305	0.016	0.406	0.018	0.457	0.018	0.457	0.022	0.559	
	± 0.003	± 0.076	± 0.006	± 0.152	± 0.008	± 0.203	± 0.010	± 0.254	± 0.010	± 0.254	± 0.010	± 0.254	± 0.012	± 0.305	
СВ	0.012	0.305	0.018	0.457	0.022	0.559	0.040	1.016	0.045	1.143	0.045	1.143	0.045	1.143	
	± 0.003	± 0.076	± 0.004	± 0.102	± 0.005	± 0.127	± 0.005	± 0.127	± 0.005	± 0.127	± 0.005	± 0.127	± 0.005	± 0.127	



Electrical Characteristics

Туре	NP0	X7R			
Temperature Coefficient	0±30ppm/°C (-55 to +125°C)	±15% (-55 to +125°C)			
Dielectric Strength	Vrated ≤100VDC: DWV = 2.5 X WVDC, 25°C, 50m Vrated = 500VDC: DWV = 1.5 X WVDC, 25°C, 50m				
Disspation Factor	0.1% max.	WVDC ≥ 50 VDC: 2.5% max. WVDC = 25 VDC: 3.5% max. WVDC = 10-16 VDC: 5.0% max. WVDC = 6.3 VDC: 10% max			
Insulation Resistance (Min @ 25°C WVDC)	C≤ 0.047 μ F: 1000 Ω F or 100 G Ω , whichever is les C> 0.047 μ F: 500 Ω F or 10 G Ω , whichever is less	s			
Test Conditions	C > 100 pF; 1kHz ±50Hz; 1.0±0.2 VRMS C ≤ 100 pF; 1Mhz ±50kHz; 1.0±0.2 VRMS	1.0kHz±50Hz @ 1.0±0.2 Vrms			